

# TPM1919-40

## FEATURES :

■ HIGH POWER

$P_{1dB} = 46.0 \text{ dBm}$  at 1.9 GHz

■ HIGH GAIN

$G_{1dB} = 13 \text{ dB}$  at 1.9 GHz

■ PARTIALLY MATCHED TYPE

■ HERMETICALLY SEALED PACKAGE

## RF PERFORMANCE SPECIFICATIONS ( $T_a = 25^\circ\text{C}$ )

CHARACTERISTICS	SYMBOL	CONDITION	UNIT	MIN.	TYP.	MAX.
Output Power at 1dB Compression Point	$P_{1dB}$	$V_{DS} = 10 \text{ V}$ $f = 1.9 \text{ GHz}$	dBm	45.0	46.0	—
Power Gain at 1dB Compression Point	$G_{1dB}$		dB	12.0	13.0	—
Drain Current	$I_{DS}$		A	—	8.0	9.0
Power Added Efficiency	$\eta_{add}$		%	—	47	—
Channel-Temperature Rise	$\Delta T_{ch}$		$V_{DS} \times I_{DS} \times R_{th(c-c)}$	$^\circ\text{C}$	—	—

## ELECTRICAL CHARACTERISTICS ( $T_a = 25^\circ\text{C}$ )

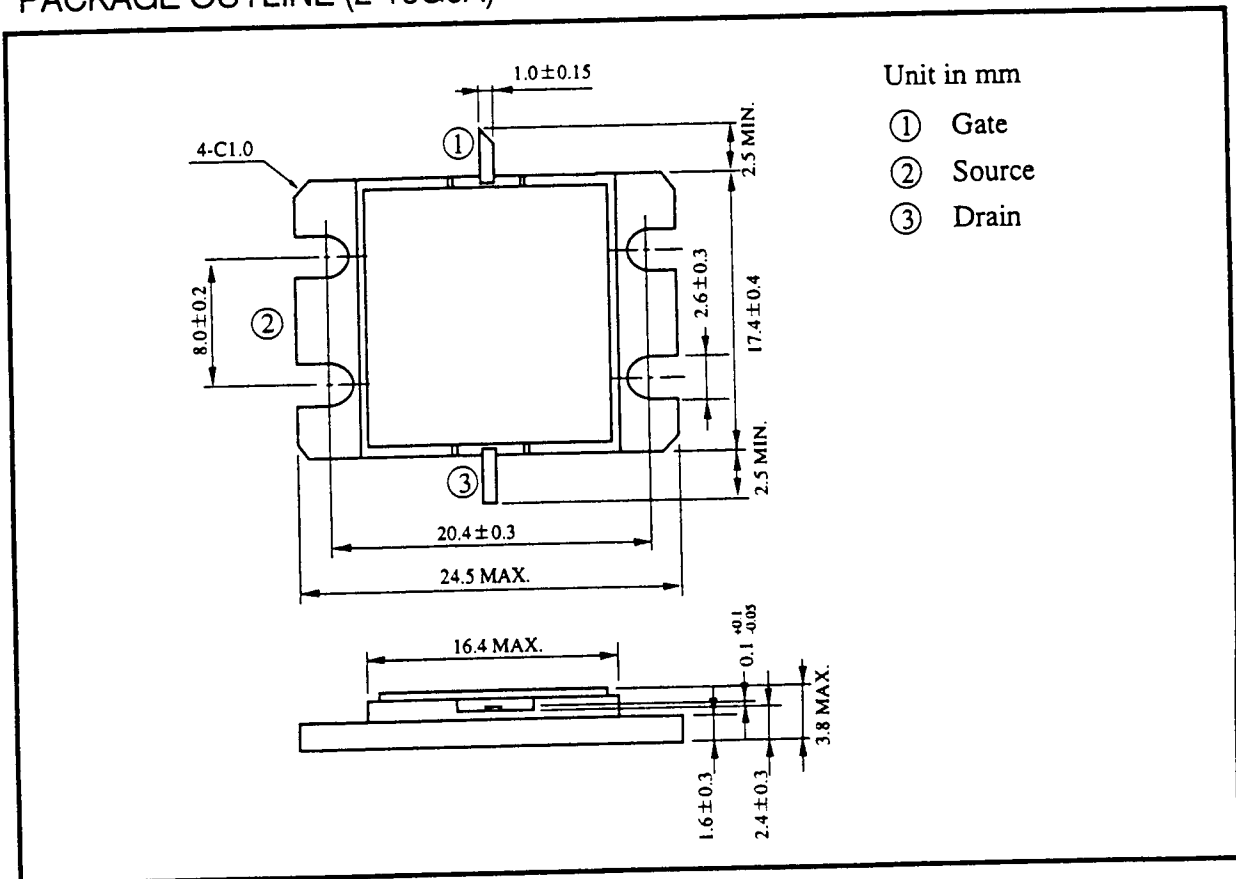
CHARACTERISTICS	SYMBOL	CONDITION	UNIT	MIN.	TYP.	MAX.
Transconductance	$g_m$	$V_{DS} = 3 \text{ V}$ $I_{DS} = 8.0 \text{ A}$	mS	—	8000	—
Pinch-off Voltage	$V_{GSoff}$	$V_{DS} = 3 \text{ V}$ $I_{DS} = 170 \text{ mA}$	V	-1.0	-2.5	-4.0
Saturated Drain Current	$I_{DSS}$	$V_{DS} = 3 \text{ V}$ $V_{GS} = 0 \text{ V}$	A	—	20	26
Gate-Source Breakdown Voltage	$V_{GSO}$	$I_{GS} = -500 \mu\text{A}$	V	-5	—	—
Thermal Resistance	$R_{th(c-c)}$	Channel to Case	$^\circ\text{C/W}$	—	0.8	1.2

\* RECOMMENDED GATE RESISTANCE ( $R_g$ ) :  $R_g = 30 \Omega$  (MAX.)

ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTICS	SYMBOL	UNIT	RATING
Drain-Source Voltage	V <sub>DS</sub>	V	15
Gate-Source Voltage	V <sub>GS</sub>	V	-5
Drain Current	I <sub>DS</sub>	A	26
Total Power Dissipation (T <sub>C</sub> = 25°C)	P <sub>T</sub>	W	100
Channel Temperature	T <sub>ch</sub>	°C	175
Storage Temperature	T <sub>stg</sub>	°C	-65~175

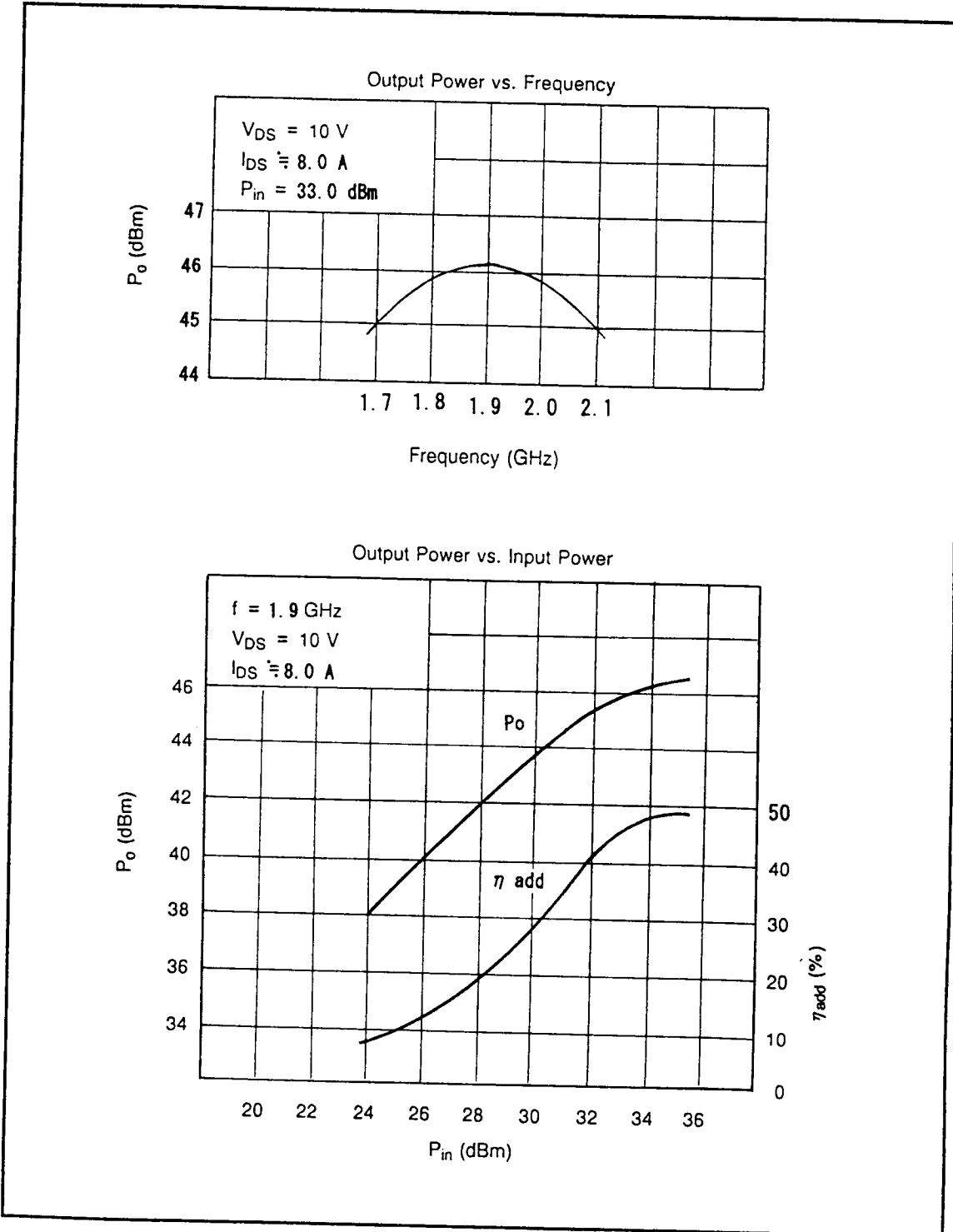
PACKAGE OUTLINE (2-16G6A)



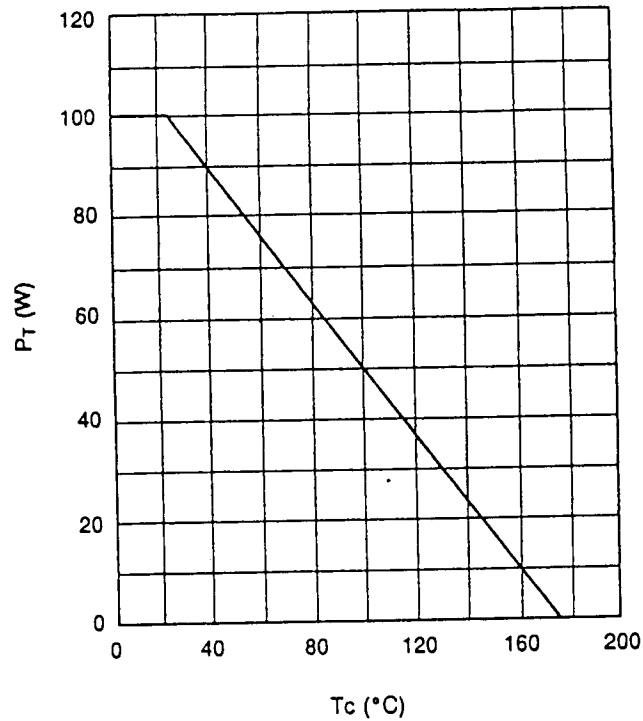
HANDLING PRECAUTIONS FOR PACKAGED TYPE

Soldering iron should be grounded and the operating time should not exceed 10 seconds at 260°C.

RF PERFORMANCES



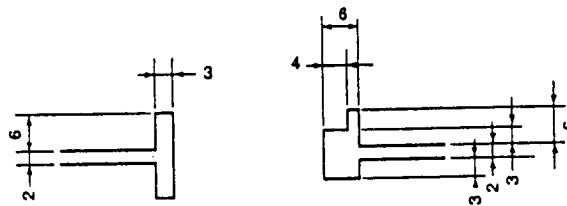
**POWER DISSIPATION VS. CASE TEMPERATURE**



**DRAWING OF MATCHING NETWORK**

INPUT

OUTPUT



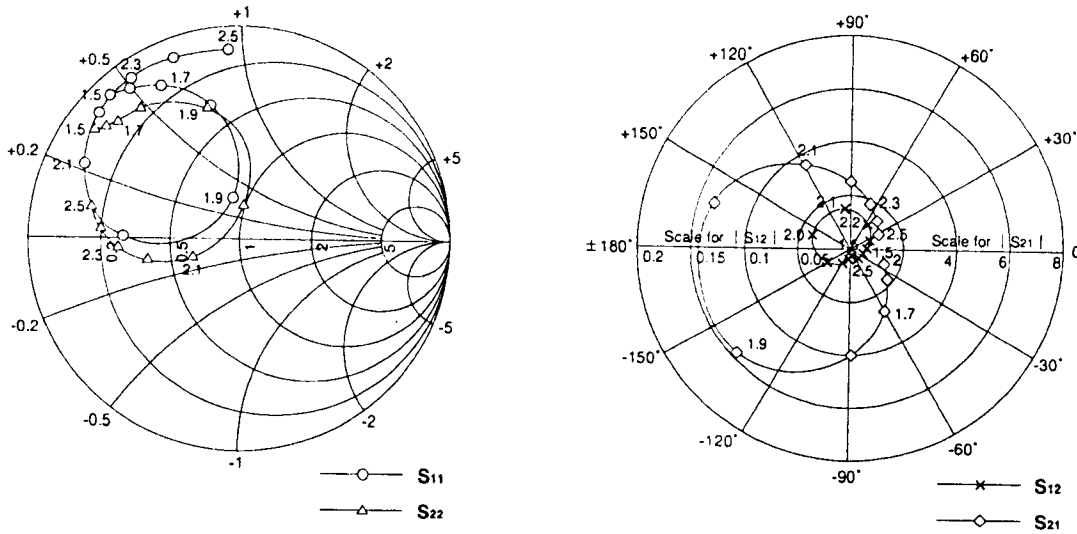
Unit in mm

Substrate Material : Teflon ( $\epsilon r = 2.8$ )  
 Thickness : 0.76mm

**TPM1919-40 S-PARAMETERS  
(MAGN.and ANGLES)**

$V_{DS} = 10V, I_{DS} = 8A$

$f = 1.5 \sim 2.5GHz$



FREQUENCY (MHz)	$S_{11}$		$S_{21}$		$S_{12}$		$S_{22}$	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
1500	0.913	133	1.392	-23	0.007	-75	0.856	144
1600	0.881	127	1.848	-39	0.010	-95	0.827	141
1700	0.810	118	2.614	-60	0.015	-118	0.800	137
1800	0.641	103	3.966	-89	0.024	-150	0.771	128
1900	0.201	100	5.791	-137	0.038	160	0.631	105
2000	0.551	179	5.406	162	0.039	98	0.172	83
2100	0.820	155	3.628	119	0.028	54	0.235	-160
2200	0.891	139	2.483	90	0.020	24	0.445	-167
2300	0.906	125	1.817	67	0.016	2	0.574	-176
2400	0.906	111	1.421	47	0.013	-18	0.657	176
2500	0.895	94	1.179	28	0.012	-36	0.721	168